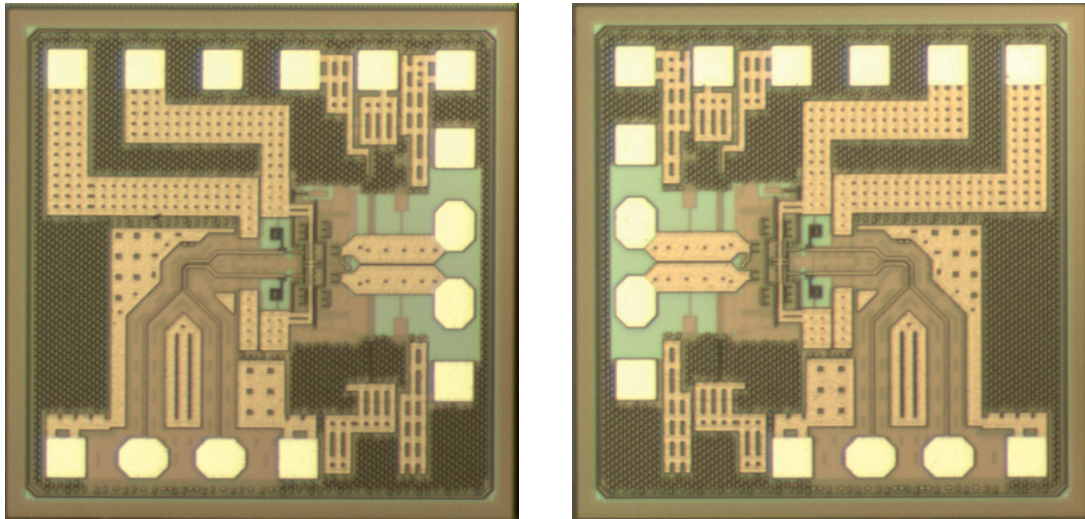


# LOW-POWER 32 GBd LINEAR OPTICAL MODULATOR DRIVER



## AT A GLANCE

32 GBd linear differential driver for telecom and datacom applications



### Features

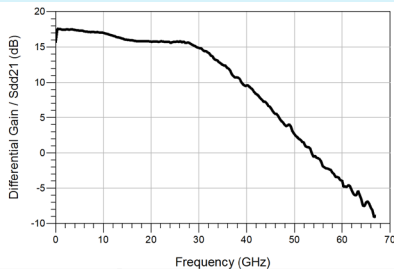
- Differential input and differential output
- Open-collector outputs
- Ultra-low power, 270 mW
- Linear Driver
- 3.0V<sub>pp</sub> differential output at 2 x 25 Ω loads
- Integrated output peak-level detectors
- 90°-bended RF input, mirrored IC available

### Applications

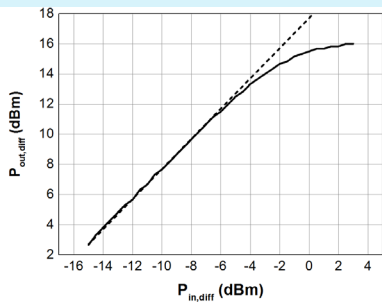
- Mach-Zehnder modulator driver
- Supports NRZ, PAM-4 Signals
- Broadband signal amplification

### Low-power open-collector SiGe Driver IC

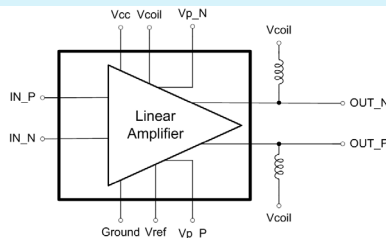
HHI provides open-collector SiGe linear driver IC for InP Mach-Zehnder modulator. Its differential output is suitable to drive InP Mach-Zehnder modulator having 2x 25 Ω. It integrates output peak-level detectors and consumes 270 mW per channel. It enables the electro-optical module to consume the lowest power.



Differential S<sub>21</sub> measurement result  
(P<sub>in,diff</sub> = -20 dBm, Temp = 23°C,  
Z<sub>in,diff</sub> = 100Ω, Z<sub>Load,diff</sub> = 50Ω)



1-dB compression point at 1 GHz (40°C)



Circuit Block Diagram



Dr. Jung Han Choi  
InP and RF

Phone +49 30 31002-471  
jung-han.choi@hhi.fraunhofer.de

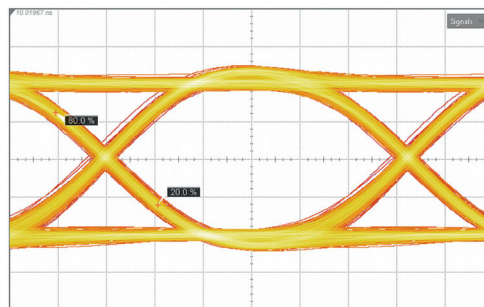
Fraunhofer Heinrich Hertz Institute  
Einsteinufer 37, 10587 Berlin  
Germany

www.hhi.fraunhofer.de/pir

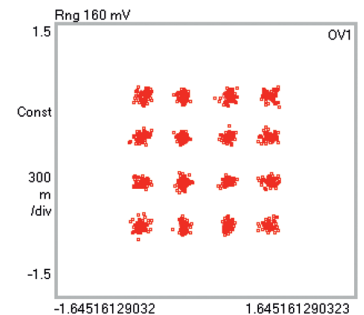
## Specifications

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Bandwidth	BW		30		GHz	
Power	P		270		mW	
Data Rate	DR		32		Gb/s	
Rise / fall time	t/t <sub>f</sub>		10		ps	20 % - 80 %
Gain*			17.5		dB	Differential S <sub>21</sub> Z <sub>in,diff</sub> = 100Ω, Z <sub>Load,diff</sub> = 50Ω
Group Delay Distortion*	GD			±5	ps	
Jitter (rms)			523		fs	
Jitter(p-p)			3.47		ps	
Differential Input Signal	V <sub>IN,P</sub> - V <sub>IN,N</sub>		600		mV <sub>pp</sub>	AC-coupled
Differential Output Signal	V <sub>OUT,P</sub> - V <sub>OUT,N</sub>		3000		mV <sub>pp</sub>	2 x 25 Ω load
P <sub>1dB</sub>	P <sub>1dB</sub>	13,6		14,4	dBm	output-referred, Z <sub>Load,diff</sub> = 50Ω
THD	THD		3.7		%	1 GHz, 3V <sub>pp</sub> output conditions
CMRR*	CMRR		14		dB	up to 20 GHz
Input Reflection*	S <sub>dd11</sub>			DC < f < 8 GHz 8 GHz < f < 24 GHz 24 GHz < f < BW	-19 -9 -8	Differential input
Output Peak-level detector			170 mV		V/V <sub>pp,diff</sub>	Z <sub>Load,diff</sub> = 50Ω, each output (V <sub>p_N</sub> , V <sub>p_P</sub> ) referenced to Vref
Operation Temperature			40		°C	

\* denotes that measurements were carried out at room temperature condition, 23°C. Unless noted, measurement temperature is 40°C.



Electrical eye waveform at 32 Gb/s  
(5ps/div, 700mV/div, 40°C)



Electro-optical QAM-16 Constellation at 32 Gb/s, EVM: 6.4%rms